## NSN 5961-01-193-8436

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## Inclosure Material:

Metal

**Overall Length:** 

0.260 inches

## Terminal Length:

1.500 inches

## **Overall Diameter:**

0.370 inches

## Internal Configuration:

Junction contact

## Joint Electronic Device Engineering Council/jedec/case Outline Designation:

### To-5

Electrode Internally-electrically Connected To Case:

Collector

### **Mounting Method:**

Terminal

## Terminal Circle Diameter:

0.200 inches

## **Features Provided:**

Hermetically sealed case

## Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

120.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 7.0 emitter to base voltage, static, collector open

## **Current Rating Per Characteristic:**

1.00 amperes source cutoff current

## Power Rating Per Characteristic:

800.0 milliwatts small-signal input power, common-collector preset

### Transfer Ratio:

30.0 small-signal short-circuit forward current transfer ratio, common-emitter

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

### **Special Features:**

Junction pattern arrangement: npn

### **Terminal Type And Quantity:**

3 uninsulated wire lead

### Shelf Life:

N/a

### Unit Of Measure:

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#### Demilitarization:

No

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